

## Triacs

### Silicon Bidirectional Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

#### Features

- Small Size Surface Mount DPAK Package
- Passivated Die for Reliability and Uniformity
- Blocking Voltage to 800 V
- On-State Current Rating of 4.0 A RMS at 108°C
- High Immunity to  $dv/dt$  – 500 V/ $\mu$ s at 125°C
- High Immunity to  $di/dt$  – 6.0 A/ms at 125°C
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V  
Machine Model, C > 400 V
- Pb-Free Packages are Available

#### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

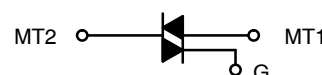
Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) ( $T_J = -40$ to $125^\circ\text{C}$ , Sine Wave, 50 to 60 Hz, Gate Open) MAC4DCM MAC4DCN	$V_{\text{DRM}}$ , $V_{\text{RRM}}$	600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_C = 108^\circ\text{C}$ )	$I_{\text{T(RMS)}}$	4.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_J = 125^\circ\text{C}$ )	$I_{\text{TSM}}$	40	A
Circuit Fusing Consideration ( $t = 8.3$ msec)	$I^2t$	6.6	$\text{A}^2\text{sec}$
Peak Gate Power (Pulse Width $\leq 10$ $\mu\text{sec}$ , $T_C = 108^\circ\text{C}$ )	$P_{\text{GM}}$	2.0	W
Average Gate Power ( $t = 8.3$ msec, $T_C = 108^\circ\text{C}$ )	$P_{\text{G(AV)}}$	1.0	W
Peak Gate Current (Pulse Width $\leq 20$ $\mu\text{sec}$ , $T_C = 108^\circ\text{C}$ )	$I_{\text{GM}}$	4.0	A
Peak Gate Voltage (Pulse Width $\leq 20$ $\mu\text{sec}$ , $T_C = 108^\circ\text{C}$ )	$V_{\text{GM}}$	5.0	V
Operating Junction Temperature Range	$T_J$	$-40$ to $125$	$^\circ\text{C}$
Storage Temperature Range	$T_{\text{stg}}$	$-40$ to $150$	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

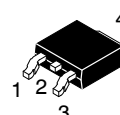
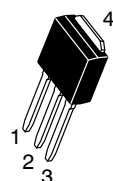
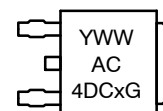
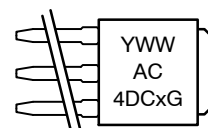
1.  $V_{\text{DRM}}$  and  $V_{\text{RRM}}$  for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.

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### TRIACS 4.0 AMPERES RMS 600 – 800 VOLTS



#### MARKING DIAGRAMS

**DPAK  
CASE 369C  
STYLE 6****DPAK-3  
CASE 369D  
STYLE 6**

Y = Year  
WW = Work Week  
AC4DCx = Device Code  
x = M or N  
G = Pb-Free Package

#### PIN ASSIGNMENT

	PIN ASSIGNMENT
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

# MAC4DCM, MAC4DCN

## THERMAL CHARACTERISTICS

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Characteristic	Symbol	Max	Unit
Thermal Resistance, – Junction-to-Case – Junction-to-Ambient – Junction-to-Ambient (Note 2)	$R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$	3.5 88 80	$^{\circ}\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes (Note 3)	$T_L$	260	$^{\circ}\text{C}$

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^{\circ}\text{C}$ unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Peak Repetitive Blocking Current ( $V_D = \text{Rated } V_{DRM}$ , $V_{RRM}$ ; Gate Open) $T_J = 25^{\circ}\text{C}$ $T_J = 125^{\circ}\text{C}$	$I_{DRM}$ , $I_{RRM}$	– –	– –	0.01 2.0	mA
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### ON CHARACTERISTICS

Peak On-State Voltage (Note 4) ( $I_{TM} = \pm 6.0 \text{ A}$ )	$V_{TM}$	–	1.3	1.6	V
Gate Trigger Current (Continuous dc) ( $V_D = 12 \text{ V}$ , $R_L = 100 \Omega$ ) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	$I_{GT}$	8.0 8.0 8.0	12 18 22	35 35 35	mA
Gate Trigger Voltage (Continuous dc) ( $V_D = 12 \text{ V}$ , $R_L = 100 \Omega$ ) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	$V_{GT}$	0.5 0.5 0.5	0.8 0.8 0.8	1.3 1.3 1.3	V
Gate Non-Trigger Voltage (Continuous dc) ( $V_D = 12 \text{ V}$ , $R_L = 100 \Omega$ ) MT2(+), G(+); MT2(+), G(–); MT2(–), G(–) $T_J = 125^{\circ}\text{C}$	$V_{GD}$	0.2	0.4	–	V
Holding Current ( $V_D = 12 \text{ V}$ , Gate Open, Initiating Current = $\pm 200 \text{ mA}$ )	$I_H$	6.0	22	35	mA
Latching Current ( $V_D = 12 \text{ V}$ , $I_G = 35 \text{ mA}$ ) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	$I_L$	– – –	30 50 20	60 80 60	mA

### DYNAMIC CHARACTERISTICS

Rate of Change of Commutating Current ( $V_D = 400 \text{ V}$ , $I_{TM} = 4.0 \text{ A}$ , Commutating $dv/dt = 18 \text{ V}/\mu\text{sec}$ , Gate Open, $T_J = 125^{\circ}\text{C}$ , $f = 250 \text{ Hz}$ , $CL = 5.0 \mu\text{F}$ , $LL = 20 \text{ mH}$ , No Snubber) (See Figure 16)	$di/dt(c)$	6.0	8.4	–	A/ms
Critical Rate of Rise of Off-State Voltage ( $V_D = 0.67 \times \text{Rated } V_{DRM}$ , Exponential Waveform, Gate Open, $T_J = 125^{\circ}\text{C}$ )	$dv/dt$	500	1700	–	V/ $\mu\text{s}$

- These ratings are applicable when surface mounted on the minimum pad sizes recommended.
- 1/8" from case for 10 seconds.
- Pulse Test: Pulse Width  $\leq 2.0 \text{ msec}$ , Duty Cycle  $\leq 2\%$ .

### ORDERING INFORMATION

Device	Package Type	Package	Shipping <sup>†</sup>
MAC4DCM-001	DPAK-3	369D	75 Units / Rail
MAC4DCM-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail
MAC4DCMT4	DPAK	369C	2500 / Tape & Reel
MAC4DCMT4G	DPAK (Pb-Free)	369C	2500 / Tape & Reel
MAC4DCN-001	DPAK-3	369D	75 Units / Rail
MAC4DCN-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail
MAC4DCNT4	DPAK	369C	2500 / Tape & Reel
MAC4DCNT4G	DPAK (Pb-Free)	369C	2500 / Tape & Reel

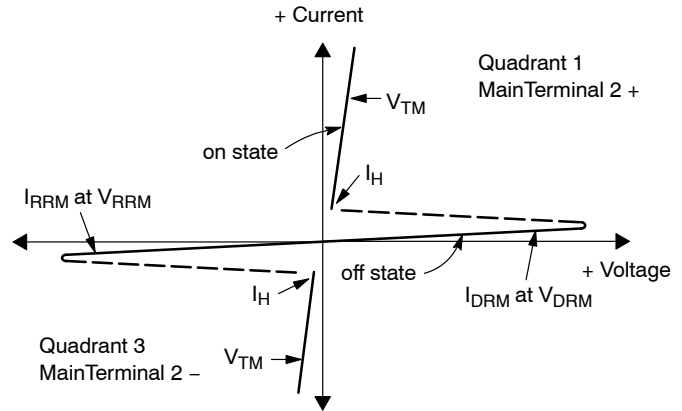
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MAC4DCM, MAC4DCN

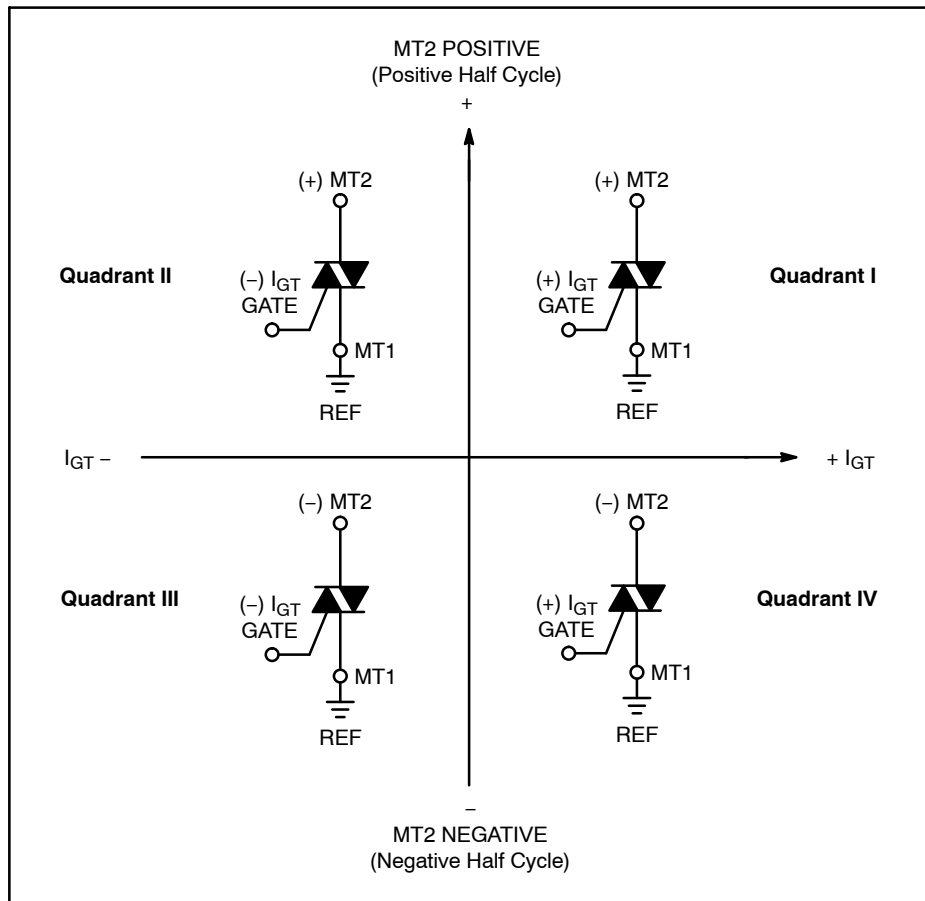
[查询"MAC4DCM-D"供应商](#)

## Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off-State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off-State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On-State Voltage
$I_H$	Holding Current



### Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

# MAC4DCM, MAC4DCN

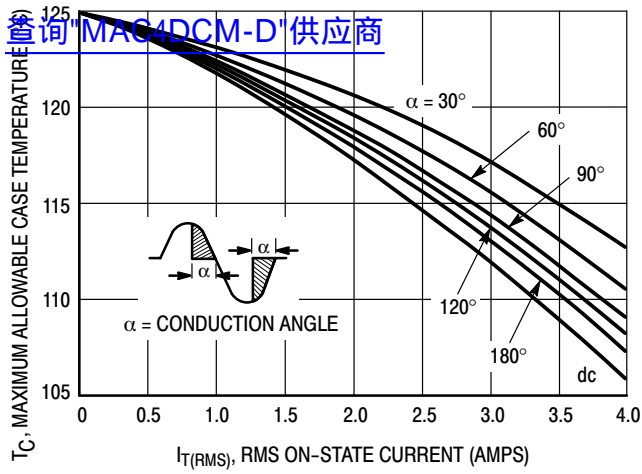


Figure 1. RMS Current Derating

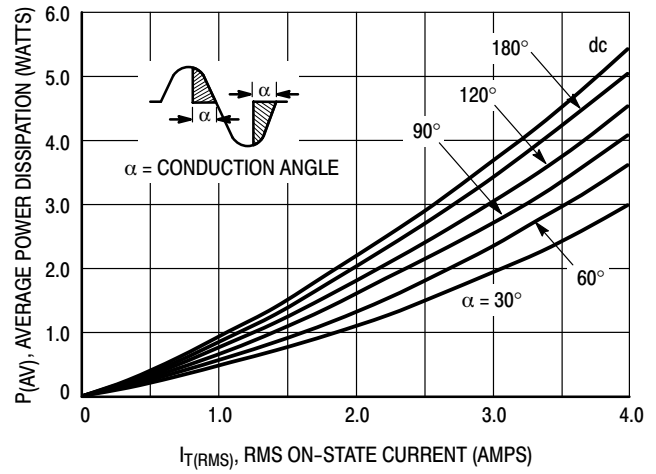


Figure 2. On-State Power Dissipation

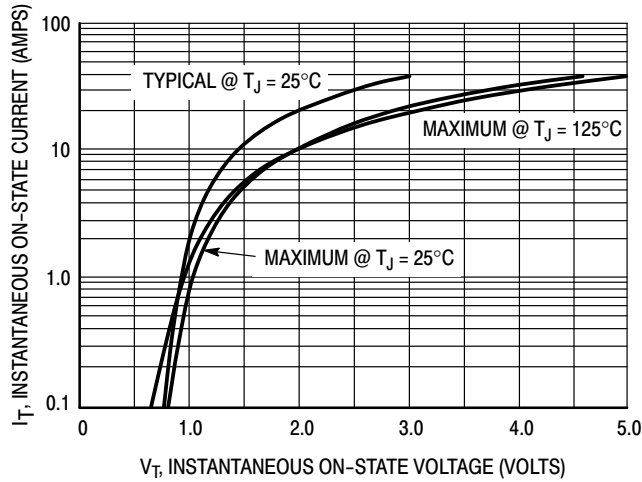


Figure 3. On-State Characteristics

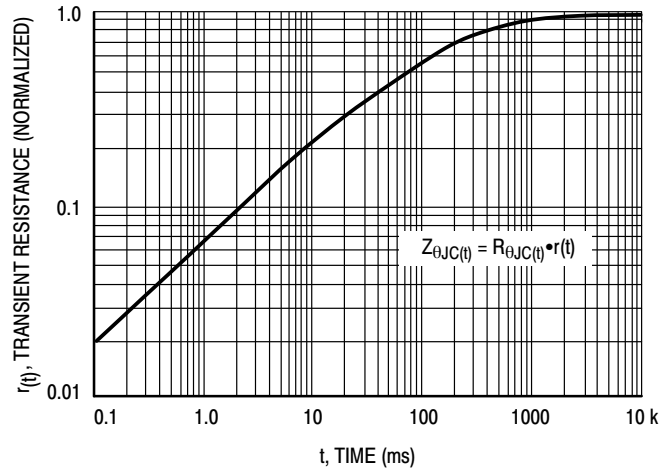


Figure 4. Transient Thermal Response

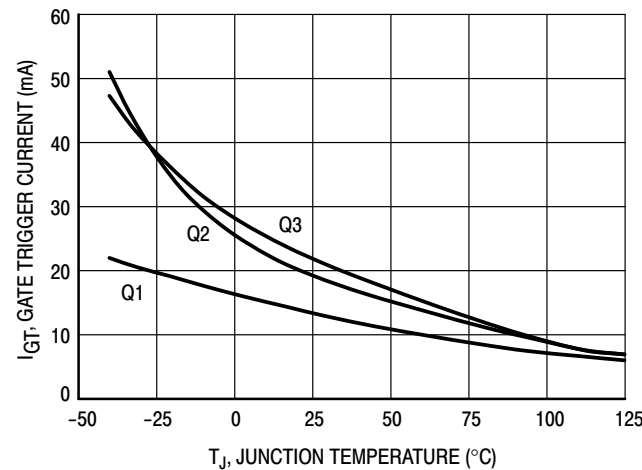


Figure 5. Typical Gate Trigger Current versus Junction Temperature

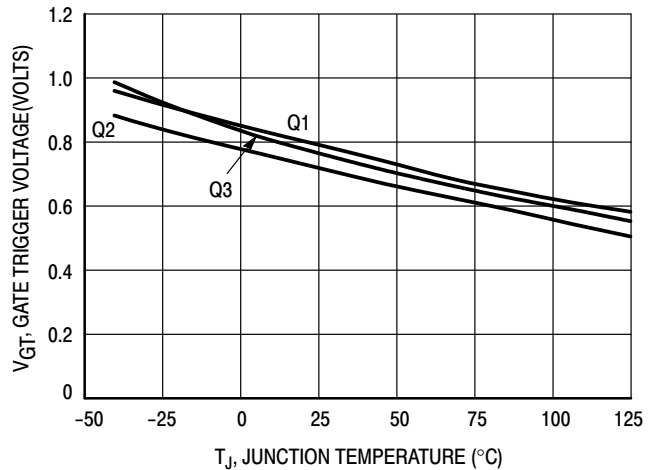
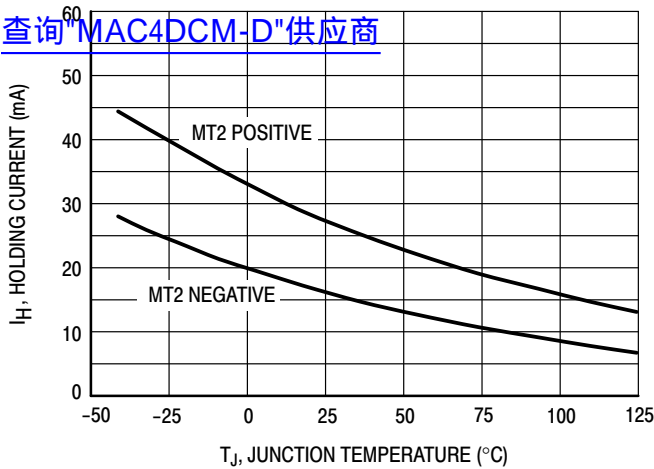


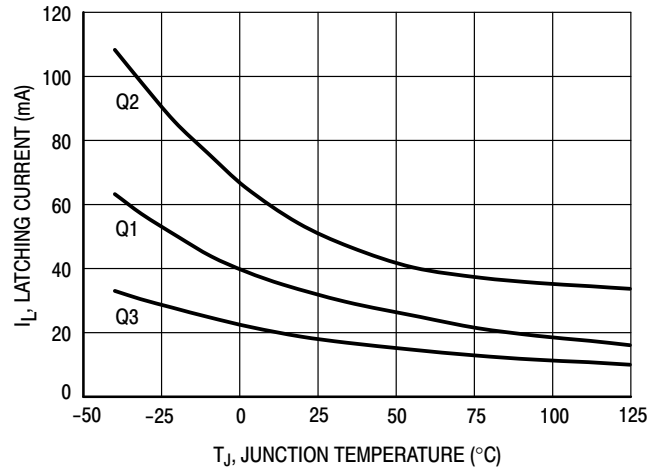
Figure 6. Typical Gate Trigger Voltage versus Junction Temperature

# MAC4DCM, MAC4DCN

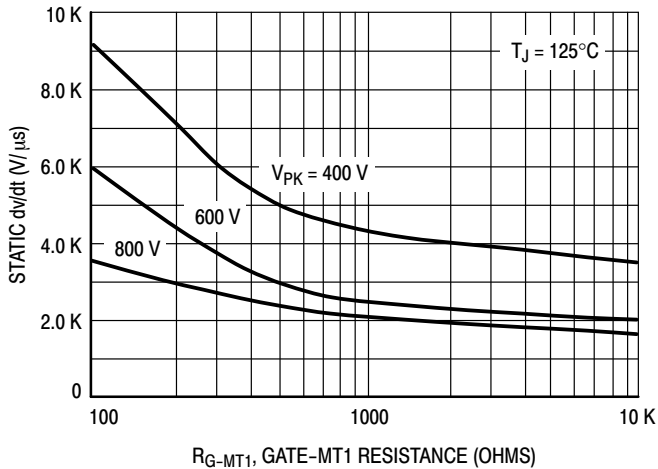
查询"MAC4DCM-D"供应商



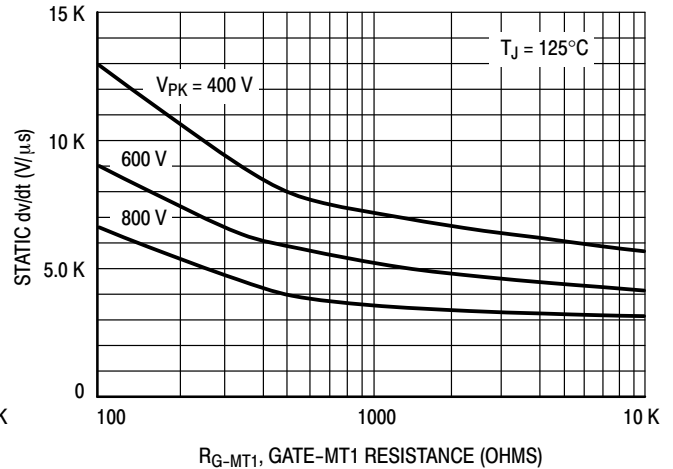
**Figure 7. Typical Holding Current versus Junction Temperature**



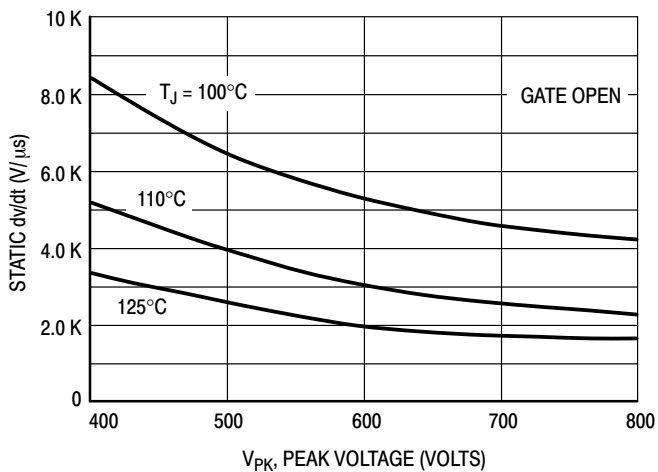
**Figure 8. Typical Latching Current versus Junction Temperature**



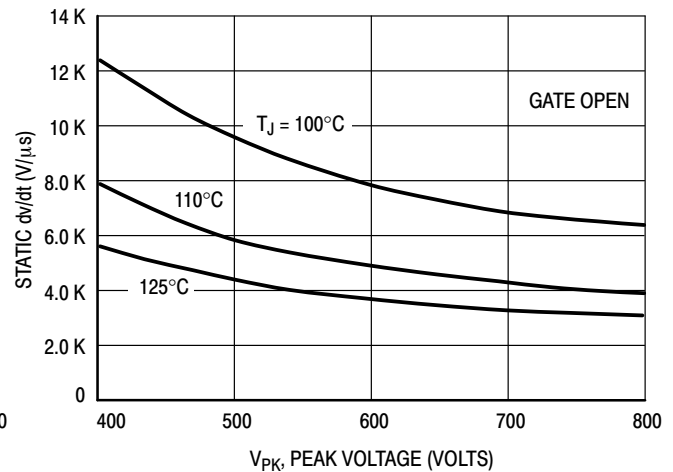
**Figure 9. Exponential Static dv/dt versus Gate-MT1 Resistance, MT2(+)**



**Figure 10. Exponential Static dv/dt versus Gate-MT1 Resistance, MT2(-)**



**Figure 11. Exponential Static dv/dt versus Peak Voltage, MT2(+)**



**Figure 12. Exponential Static dv/dt versus Peak Voltage, MT2(-)**

## MAC4DCM, MAC4DCN

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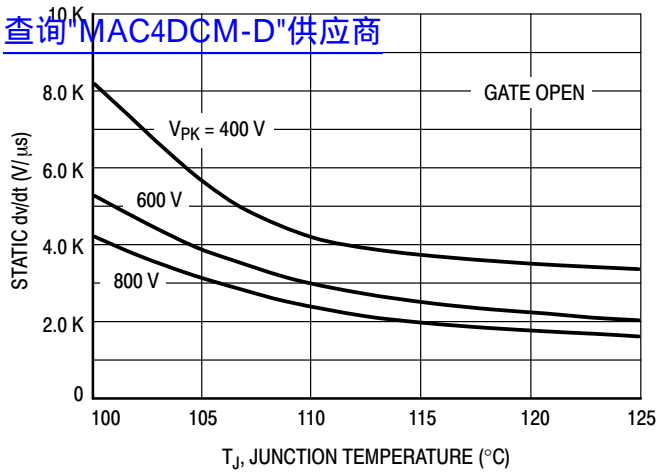


Figure 13. Typical Exponential Static dv/dt versus Junction Temperature, MT2(+)

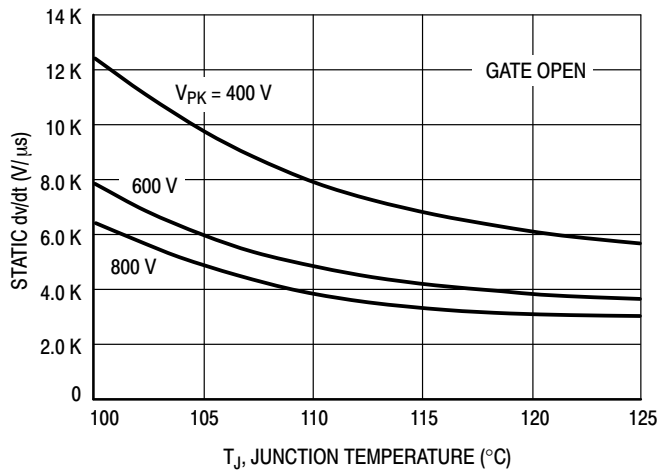


Figure 14. Typical Exponential Static dv/dt versus Junction Temperature, MT2(-)

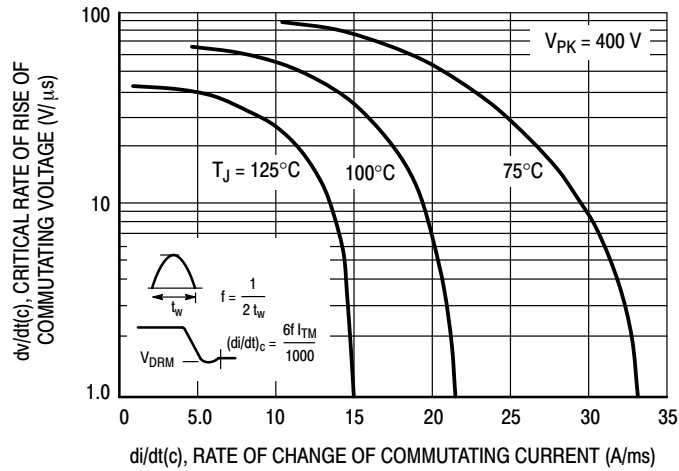
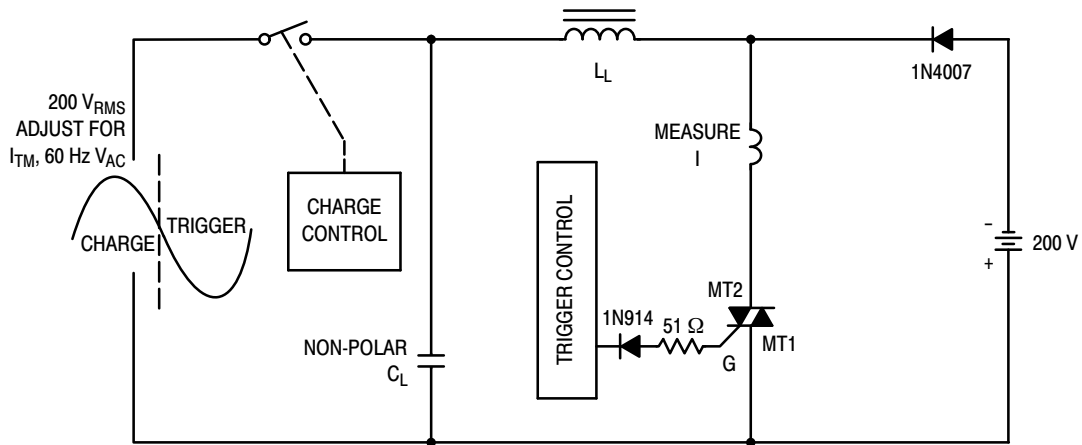


Figure 15. Critical Rate of Rise of Commutating Voltage



Note: Component values are for verification of rated  $(di/dt)_c$ . See AN1048 for additional information.

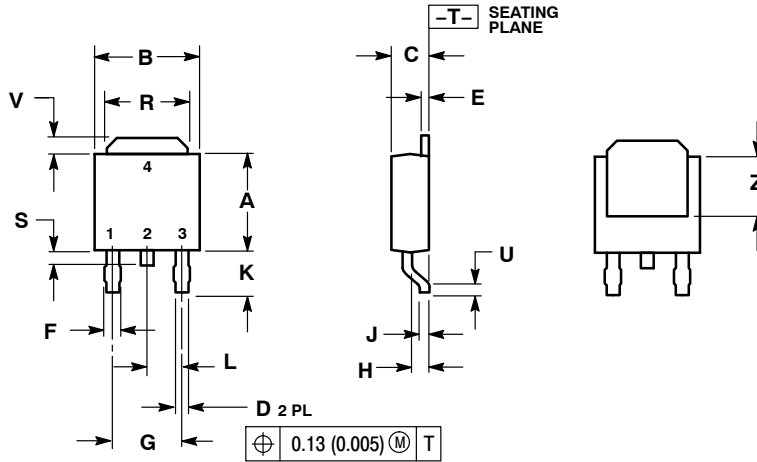
Figure 16. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current  $(di/dt)_c$

# MAC4DCM, MAC4DCN

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## PACKAGE DIMENSIONS

**DPAK**  
CASE 369C  
ISSUE O

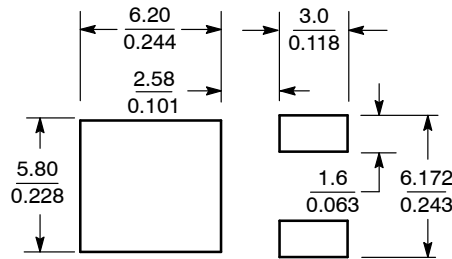


NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.22
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.180	0.215	4.57	5.45
S	0.025	0.040	0.63	1.01
U	0.020	---	0.51	---
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

STYLE 6:  
PIN 1. MT1  
2. MT2  
3. GATE  
4. MT2

## SOLDERING FOOTPRINT\*



SCALE 3:1  $\left( \frac{\text{mm}}{\text{inches}} \right)$

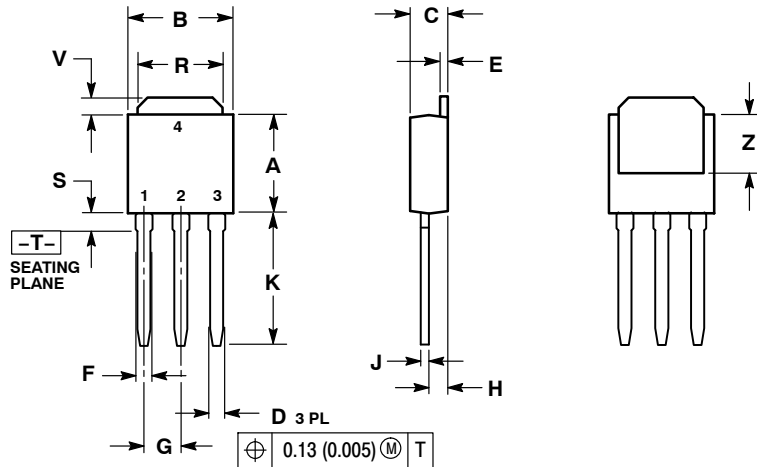
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MAC4DCM, MAC4DCN

[查询"MAC4DCM-D"供应商](#)

## PACKAGE DIMENSIONS

DPAK-3  
CASE 369D-01  
ISSUE B




### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29	BSC
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

### STYLE 6:

- PIN 1. MT1  
2. MT2  
3. GATE  
4. MT2

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